

REVISIONS																			
LTR	DESCRIPTION													DATE (YR-MO-DA)	APPROVED				

REV																			
SHEET																			
REV																			
SHEET																			

REV STATUS OF SHEETS	REV																		
	SHEET	1	2	3	4	5	6	7	8	9	10	11							

PMIC N/A	PREPARED BY RICK C. OFFICER	DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444																	
<b>STANDARDIZED MILITARY DRAWING</b>  THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE  AMSC N/A	CHECKED BY CHARLES E. BESORE	MICROCIRCUIT, LINEAR, VIDEO OPERATIONAL AMPLIFIER, MONOLITHIC SILICON																	
	APPROVED BY MICHAEL A. FRYE																		
	DRAWING APPROVAL DATE 93-06-09	SIZE <b>A</b>	CAGE CODE <b>67268</b>	<b>5962-93131</b>															
	REVISION LEVEL	SHEET 1		OF 11															<b>1</b>

DESC FORM 133  
JUL 91

5962-E277-93

DISTRIBUTION STATEMENT A. Approved for public release; distribution is unlimited.



1.3 Absolute maximum ratings. 1/

Supply voltage ( $\pm V_S$ ) . . . . .	$\pm 18$ V dc
Common mode input voltage ( $V_{CM}$ ) . . . . .	$\pm V_S$
Differential input voltage ( $V_{ID}$ ) . . . . .	$\pm 6$ V dc
Power dissipation ( $P_D$ ):	
Case P . . . . .	1.3 W
Case 2 . . . . .	2.1 W
Lead temperature range (soldering 60 seconds) . . . . .	300°C
Storage temperature range . . . . .	-65°C to +150°C
Thermal resistance, junction-to-case ( $\Theta_{JC}$ ) . . . . .	See MIL-STD-1835
Thermal resistance, junction-to ambient ( $\Theta_{JA}$ ):	
Case P . . . . .	110°C/W
Case 2 . . . . .	70°C/W

1.4 Recommended operating conditions.

Power supply voltage range ( $\pm V_S$ ) . . . . .	$\pm 4.5$ V to $\pm 18$ V
Ambient operating temperature range ( $T_A$ ) . . . . .	-55°C to +125°C

2. APPLICABLE DOCUMENTS

2.1 Government specifications, standards, bulletin, and handbook. Unless otherwise specified, the following specifications, standards, bulletin, and handbook of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATIONS

MILITARY

- MIL-M-38510 - Microcircuits, General Specification for.
- MIL-I-38535 - Integrated Circuits, Manufacturing, General Specification for.

STANDARDS

MILITARY

- MIL-STD-480 - Configuration Control-Engineering Changes, Deviations and Waivers.
- MIL-STD-883 - Test Methods and Procedures for Microelectronics.
- MIL-STD-1835 - Microcircuit Case Outlines.

BULLETIN

MILITARY

- MIL-BUL-103 - List of Standardized Military Drawings (SMD's).

HANDBOOK

MILITARY

- MIL-HDBK-780 - Standardized Military Drawings.

(Copies of the specifications, standards, bulletin, and handbook required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

1/ Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.  
 2/ Maximum power dissipation is specified so that  $T_J$  does not exceed +175°C at an ambient temperatures of +25°C. Derate above  $T_A = +25^\circ\text{C}$  for case P at 9 mW/°C and case 2 at 14 mW/°C.

<b>STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444</b>	<b>SIZE A</b>		<b>5962-93131</b>
		<b>REVISION LEVEL</b>	<b>SHEET 3</b>

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements for device class M shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein. The individual item requirements for device classes B and S shall be in accordance with MIL-M-38510 and as specified herein. For device classes B and S, a full electrical characterization table for each device type shall be included in this SMD. The individual item requirements for device classes Q and V shall be in accordance with MIL-I-38535, the device manufacturer's Quality Management (QM) plan, and as specified herein.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 for device classes M, B, and S and MIL-I-38535 for device classes Q and V and herein.

3.2.1 Case outline(s). The case outline(s) shall be in accordance with 1.2.4 herein.

3.2.2 Terminal connections. The terminal connections shall be as specified on figure 1.

3.3 Electrical performance characteristics and postirradiation parameter limits. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table I and shall apply over the full ambient operating temperature range.

3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are defined in table I.

3.5 Marking. The part shall be marked with the PIN listed in 1.2 herein. Marking for device class M shall be in accordance with MIL-STD-883 (see 3.1 herein). In addition, the manufacturer's PIN may also be marked as listed in MIL-BUL-103. Marking for device classes B and S shall be in accordance with MIL-M-38510. Marking for device classes Q and V shall be in accordance with MIL-I-38535.

3.5.1 Certification/compliance mark. The compliance mark for device class M shall be a "C" as required in MIL-STD-883 (see 3.1 herein). The certification mark for device classes B and S shall be a "J" or "JAN" as required in MIL-M-38510. The certification mark for device classes Q and V shall be a "QML" as required in MIL-I-38535.

3.6 Certificate of compliance. For device class M, a certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-BUL-103 (see 6.7.3 herein). For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.7.2 herein). The certificate of compliance submitted to DESC-EC prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device class M, the requirements of MIL-STD-883 (see 3.1 herein), or for device classes Q and V, the requirements of MIL-I-38535 and the requirements herein.

3.7 Certificate of conformance. A certificate of conformance as required for device class M in MIL-STD-883 (see 3.1 herein) or device classes B and S in MIL-M-38510 or for device classes Q and V in MIL-I-38535 shall be provided with each lot of microcircuits delivered to this drawing.

3.8 Notification of change for device class M. For device class M, notification to DESC-EC of change of product (see 6.2 herein) involving devices acquired to this drawing is required for any change as defined in MIL-STD-480.

3.9 Verification and review for device class M. For device class M, DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

3.10 Microcircuit group assignment for device classes M, B, and S. Device classes M, B, and S devices covered by this drawing shall be in microcircuit group number 85 (see MIL-M-38510, appendix E).

3.11 Serialization for device class S. All device class S devices shall be serialized in accordance with MIL-M-38510.

<b>STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444</b>	<b>SIZE A</b>		<b>5962-93131</b>
		<b>REVISION LEVEL</b>	<b>SHEET 4</b>

DESC FORM 193A  
JUL 91

TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions -55°C ≤ T <sub>A</sub> ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Limits <sup>1/</sup>		Unit
					Min	Max	
Input offset voltage	V <sub>IO</sub>	V <sub>S</sub> = ±5 V, ±15 V	1	01	-3	+3	mV
			2,3		-5	+5	
Input bias current	-I <sub>IB</sub>	V <sub>S</sub> = ±5 V, ±15 V	1	01	-5	+5	μA
			2,3		-30	+30	
	+I <sub>IB</sub>		1		-10	+10	
			2,3		-25	+25	
Input bias current versus supply voltage	-I <sub>IBS</sub> +I <sub>IBS</sub>	V <sub>S</sub> = ±4.5 V to ±18 V	1,2,3	01	-2	+2	μA/V
Input bias current versus common mode voltage	-I <sub>IBCM</sub> +I <sub>IBCM</sub>	V <sub>S</sub> = ±15 V, V <sub>CM</sub> = ±10 V	1,2,3	01	-3	+3	μA/V
Open loop transresistance <sup>2/</sup>	T <sub>Z</sub>	V <sub>S</sub> = ±15 V, V <sub>OUT</sub> = ±10 V, R <sub>L</sub> = 200Ω	1,2,3	01	0.5		MΩ
		V <sub>S</sub> = ±5 V, V <sub>OUT</sub> = ±2.5 V, R <sub>L</sub> = 150Ω	1		0.25		
			2,3		0.125		
Output voltage swing	V <sub>OUT</sub>	V <sub>S</sub> = ±5 V, R <sub>L</sub> = 150Ω	1	01	-2.5	+2.5	V
			2,3		-2	+2	
		V <sub>S</sub> = ±15 V, R <sub>L</sub> = 500Ω	1		-12.5	+12.5	
			2,3		-12	+12	
Power supply quiescent current	I <sub>Q</sub>	V <sub>S</sub> = ±15 V, V <sub>OUT</sub> = 0 V	1	01		18	mA
			2,3			22	
		V <sub>S</sub> = ±5 V, V <sub>OUT</sub> = 0 V	1			16	
			2,3			20	
Power supply rejection ratio	PSRR	V <sub>S</sub> = ±4.5 V to ±18 V	1,2,3	01	60		dB

See footnotes at end of table.

<b>STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444</b>	<b>SIZE A</b>		<b>5962-93131</b>
		<b>REVISION LEVEL</b>	<b>SHEET 5</b>

DESC FORM 193A  
JUL 91

TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions -55°C ≤ T <sub>A</sub> ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Limits 1/		Unit
					Min	Max	
Common mode rejection ratio	CMRR	V <sub>S</sub> = ±5 V, V <sub>CM</sub> = ±2.5 V	1,2,3	01	50		dB
		V <sub>S</sub> = ±15 V, V <sub>CM</sub> = ±10 V			56		
Small signal bandwidth G = +2	SSBW	V <sub>S</sub> = ±15 V, R <sub>L</sub> = 150Ω, R <sub>F</sub> = 649Ω, R <sub>G</sub> = 649Ω	4	01	100		MHz
Slew rate G = -10	SR	V <sub>S</sub> = ±15 V, V <sub>OUT</sub> = 20 V <sub>pp</sub> , R <sub>F</sub> = 590Ω, R <sub>G</sub> = 55Ω, measured at -10 V to +10 V	4	01	1800		V/μs
Settling time G = -1	t <sub>S</sub>	V <sub>S</sub> = ±15 V, V <sub>OUT</sub> = ±5 V, R <sub>F</sub> = 562Ω, R <sub>G</sub> = 562Ω, 10 V step at 0.01% of the final value	9	01		200	ns

1/ The algebraic convention, whereby the most negative value is a minimum and the most positive is a maximum, is used in this table. Negative current shall be defined as conventional current flow out of a device terminal.

2/ Transresistance is defined as the amplifier's output voltage divided by the required feedback current in its inverting input. As an example, an amplifier which requires a 1 μA input current to change its output voltage by 1 V has a transresistance of 1 MΩ.

3/ If not tested, shall be guaranteed to the limits specified in table I herein.

4. QUALITY ASSURANCE PROVISIONS

4.1 Sampling and inspection. For device class M, sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein). For device classes B and S, sampling and inspection procedures shall be in accordance with MIL-M-38510 and method 5005 of MIL-STD-883, except as modified herein. For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-I-38535 and the device manufacturer's QM plan.

STANDARDIZED  
MILITARY DRAWING  
DEFENSE ELECTRONICS SUPPLY CENTER  
DAYTON, OHIO 45444

SIZE  
A

5962-93131

REVISION LEVEL

SHEET

6

Device type	01	
Case outlines	P	2
Terminal number	Terminal symbol	
1	NC	NC
2	-INPUT	NC
3	+INPUT	NC
4	-V <sub>S</sub>	NC
5	NC	NC
6	OUTPUT	-INPUT
7	+V <sub>S</sub>	NC
8	NC	+INPUT
9	---	-V <sub>S</sub>
10	---	NC
11	---	NC
12	---	NC
13	---	NC
14	---	OUTPUT
15	---	NC
16	---	+V <sub>S</sub>
17	---	NC
18	---	NC
19	---	NC
20	---	NC

N/C = No connection

FIGURE 1. Terminal connections.

<b>STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444</b>	<b>SIZE A</b>		<b>5962-93131</b>
		<b>REVISION LEVEL</b>	<b>SHEET 7</b>

DESC FORM 193A  
JUL 91

4.2 Screening. For device class M, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. For device classes B and S, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to qualification and quality conformance inspection. For device classes Q and V, screening shall be in accordance with MIL-I-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection.

4.2.1 Additional criteria for device classes M, B, and S.

a. Burn-in test, method 1015 of MIL-STD-883.

(1) Test condition A, B, C, or D. For device class M, the test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. For device classes B and S, the test circuit shall be submitted to the qualifying activity. For device classes M, B, and S, the test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015.

(2)  $T_A = +125^\circ\text{C}$ , minimum.

b. Interim and final electrical test parameters shall be as specified in table II herein.

4.2.2 Additional criteria for device classes Q and V.

a. The burn-in test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-I-38535. The burn-in test circuit shall be maintained under document revision level control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-I-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015.

b. Interim and final electrical test parameters shall be as specified in table II herein.

c. Additional screening for device class V beyond the requirements of device class Q shall be as specified in appendix B of MIL-I-38535.

4.3 Qualification inspection.

4.3.1 Qualification inspection for device classes B and S. Qualification inspection for device classes B and S shall be in accordance with MIL-M-38510. Inspections to be performed shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.5).

4.3.2 Qualification inspection for device classes Q and V. Qualification inspection for device classes Q and V shall be in accordance with MIL-I-38535. Inspections to be performed shall be those specified in MIL-I-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.5).

4.4 Conformance inspection. Quality conformance inspection for device class M shall be in accordance with MIL-STD-883 (see 3.1 herein) and as specified herein. Quality conformance inspection for device classes B and S shall be in accordance with MIL-M-38510 and as specified herein. Inspections to be performed for device classes M, B, and S shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.5). Technology conformance inspection for classes Q and V shall be in accordance with MIL-I-38535 including groups A, B, C, D, and E inspections and as specified herein except where option 2 of MIL-I-38535 permits alternate in-line control testing.

4.4.1 Group A inspection.

a. Tests shall be as specified in table II herein.

b. Subgroups 5, 6, 7, 8, 10, and 11 in table I, method 5005 of MIL-STD-883 shall be omitted.

<b>STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444</b>	<b>SIZE A</b>		<b>5962-93131</b>
		<b>REVISION LEVEL</b>	<b>SHEET 8</b>



TABLE II. Electrical test requirements.

Test requirements	Subgroups (in accordance with MIL-STD-883, method 5005, table I)			Subgroups (in accordance with MIL-I-38535, table III)	
	Device class M	Device class B	Device class S	Device class Q	Device class V
Interim electrical parameters (see 4.2)	1	1	1	1	1
Final electrical parameters (see 4.2)	1,2,3 <u>1/</u>	1,2,3 <u>1/</u>	1,2,3 <u>1/</u>	1,2,3 <u>1/</u>	1,2,3 <u>1/</u>
Group A test requirements (see 4.4)	1,2,3, 4,9	1,2,3, 4,9	1,2,3, 4,9	1,2,3, 4,9	1,2,3, 4,9
Group B end-point electrical parameters (see 4.4)	---	---	1,2,3,4, 4,9	---	---
Group C end-point electrical parameters (see 4.4)	1	1	---	1	1
Group D end-point electrical parameters (see 4.4)	1	1	1	1	1
Group E end-point electrical parameters (see 4.4)	---	---	---	---	---

1/ PDA applies to subgroup 1.

4.4.2 Group B inspection. The group B inspection end-point electrical parameters shall be as specified in table II herein. For device class S steady-state life tests, the test circuit shall be submitted to the qualifying activity.

4.4.3 Group C inspection. The group C inspection end-point electrical parameters shall be as specified in table II herein.

<b>STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444</b>	<b>SIZE A</b>		5962-93131
		REVISION LEVEL	SHEET 9

DESC FORM 193A  
JUL 91

4.4.3.1 Additional criteria for device classes M and B. Steady-state life test conditions, method 1005 of MIL-STD-883:

- a. Test condition A, B, C, or D. For device class M, the test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. For device class B, the test circuit shall be submitted to the qualifying activity. For device classes M and B, the test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005.
- b.  $T_A = +125^\circ\text{C}$ , minimum.
- c. Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

4.4.3.2 Additional criteria for device classes Q and V. The steady-state life test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-I-38535. The test circuit shall be maintained under document revision level control by the device manufacturer's TRB in accordance with MIL-I-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005.

4.4.4 Group D inspection. The group D inspection end-point electrical parameters shall be as specified in table II herein.

4.4.5 Group E inspection. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein). RHA levels for device classes B, S, Q, and V shall be M, D, R, and H and for device class M shall be M and D.

- a. End-point electrical parameters shall be as specified in table II herein.
- b. For device classes M, B, and S, the devices shall be subjected to radiation hardness assured tests as specified in MIL-M-38510 for the RHA level being tested. For device classes Q and V, the devices or test vehicle shall be subjected to radiation hardness assured tests as specified in MIL-I-38535 for the RHA level being tested. All device classes must meet the postirradiation end-point electrical parameter limits as defined in table I at  $T_A = +25^\circ\text{C} \pm 5^\circ\text{C}$ , after exposure, to the subgroups specified in table II herein.
- c. When specified in the purchase order or contract, a copy of the RHA delta limits shall be supplied.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510 for device classes M, B, and S and MIL-I-38535 for device classes Q and V.

6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.1.1 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

6.1.2 Substitutability. Device classes B and Q devices will replace device class M devices.

6.2 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-481 using DD Form 1693, Engineering Change Proposal (Short Form).

6.3 Record of users. Military and industrial users shall inform Defense Electronics Supply Center when a system application requires configuration control and which SMD's are applicable to that system. DESC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DESC-EC, telephone (513) 296-6047.

<b>STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444</b>	<b>SIZE A</b>		<b>5962-93131</b>
		<b>REVISION LEVEL</b>	<b>SHEET 10</b>

DESC FORM 193A  
JUL 91

6.4 Comments. Comments on this drawing should be directed to DESC-EC, Dayton, Ohio 45444, or telephone (513) 296-5377.

6.5 Abbreviations, symbols, and definitions. The abbreviations, symbols, and definitions used herein are defined in MIL-M-38510 and MIL-STD-1331.

6.6 One part - one part number system. The one part - one part number system described below has been developed to allow for transitions between identical generic devices covered by the four major microcircuit requirements documents (MIL-M-38510, MIL-H-38534, MIL-I-38535, and 1.2.1 of MIL-STD-883) without the necessity for the generation of unique PIN's. The four military requirements documents represent different class levels, and previously when a device manufacturer upgraded military product from one class level to another, the benefits of the upgraded product were unavailable to the Original Equipment Manufacturer (OEM), that was contractually locked into the original unique PIN. By establishing a one part number system covering all four documents, the OEM can acquire to the highest class level available for a given generic device to meet system needs without modifying the original contract parts selection criteria.

<u>Military documentation format</u>	<u>Example PIN under new system</u>	<u>Manufacturing source listing</u>	<u>Document Listing</u>
New MIL-M-38510 Military Detail Specifications (in the SMD format)	5962-XXXXZZ(B or S)YY	QPL-38510 (Part 1 or 2)	MIL-BUL-103
New MIL-H-38534 Standardized Military Drawings	5962-XXXXZZ(H or K)YY	QML-38534	MIL-BUL-103
New MIL-I-38535 Standardized Military Drawings	5962-XXXXZZ(Q or V)YY	QML-38535	MIL-BUL-103
New 1.2.1 of MIL-STD-883 Standardized Military Drawings	5962-XXXXZZ(M)YY	MIL-BUL-103	MIL-BUL-103

6.7 Sources of supply.

6.7.1 Sources of supply for device classes B and S. Sources of supply for device classes B and S are listed in QPL-38510.

6.7.2 Sources of supply for device classes Q and V. Sources of supply for device classes Q and V are listed in QML-38535. The vendors listed in QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DESC-EC and have agreed to this drawing.

6.7.3 Approved sources of supply for device class M. Approved sources of supply for class M are listed in MIL-BUL-103. The vendors listed in MIL-BUL-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DESC-EC.

<b>STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444</b>	<b>SIZE A</b>		<b>5962-93131</b>
		<b>REVISION LEVEL</b>	<b>SHEET 11</b>

DESC FORM 193A  
JUL 91